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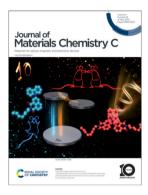
Materials for optical, magnetic and electronic devices

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Jeanne Crassous,* Lorenzo Di Bari,* Wai-Yeung Wong* and You-Xuan Zheng*

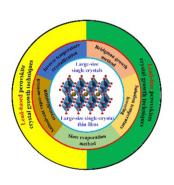


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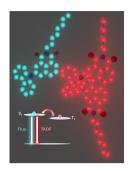
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A binaphthalimide motif as a chiral scaffold for thermally activated delayed fluorescence with circularly polarized luminescence activity

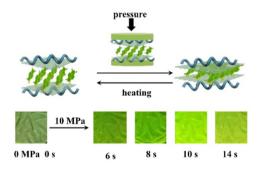
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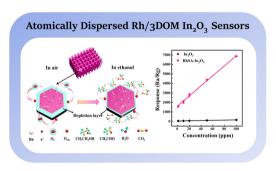
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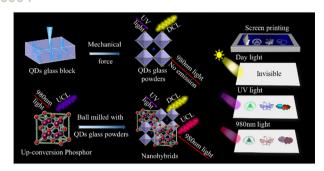
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Fubo Gu, Lanlan Zhang, Song Hong, Dongmei Han and Zhihua Wang*

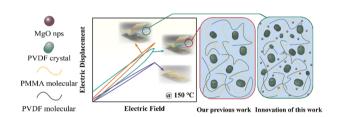


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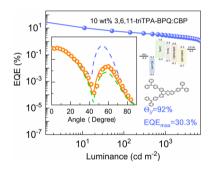
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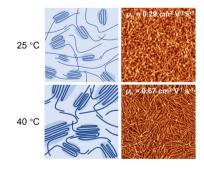
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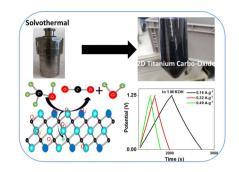
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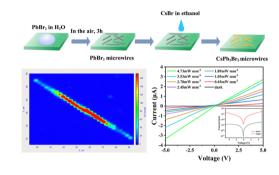
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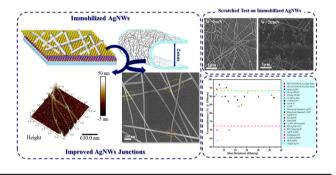
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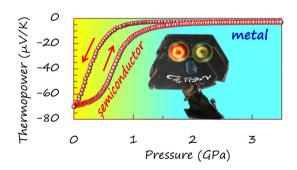
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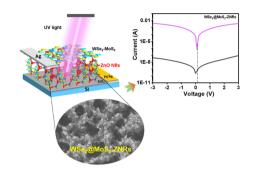
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Adhimoorthy Saravanan,* Bohr-Ran Huang,* Deepa Kathiravan, Shikha Sakalley and Sheng-Chi Chen*

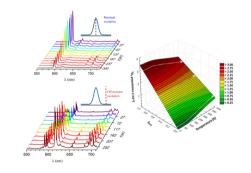
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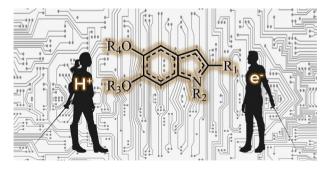
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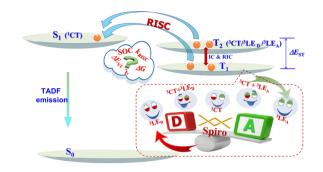
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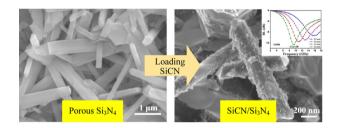
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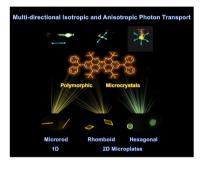
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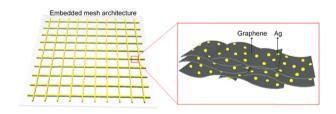
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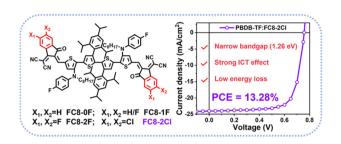
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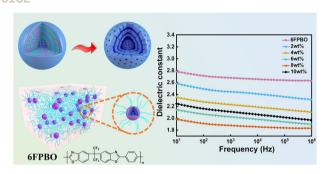
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Completely non-fused ring acceptors with low non-radiative energy loss enabled by end-group modulation

Hao Li, Jiayao Li, Chenyi Yang, Jingwen Wang, Du Hyeon Ryu, Lijiao Ma, Yi Yang, Won Suk Shin, Shaoqing Zhang* and Jianhui Hou

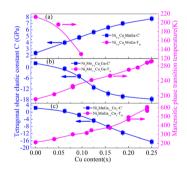
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Zhe Zhang, Peng He, Wenjun Ma, Peiyuan Zuo,* Xiaoyun Liu and Qixin Zhuang*

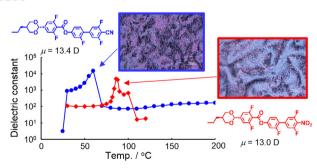
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Guijiang Li,* Lei Xu and Zhenhua Cao

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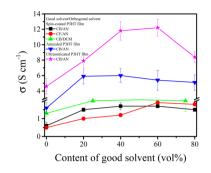
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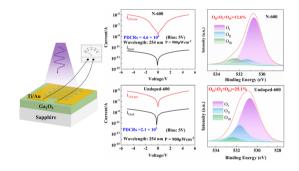
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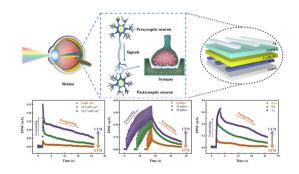
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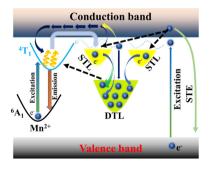
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Dayu Huang, Ziyong Cheng, Qiuyun Ouyang,* Hongzhou Lian* and Jun Lin*



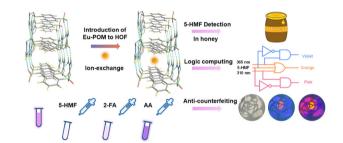
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Zishuo Zhang, Xin Xu and Bing Yan*